



Product data sheet

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General Features

 $R_{DS(ON)}$ < 19m Ω @ V_{GS}=10V

Uninterruptible power supply

V_{DS} = 40V I_D =10A

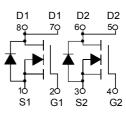
Application

Load switch

Battery protection

$\begin{array}{c} D1 \\ & D1 \\ & & D1 \\ & & & D2 \\ & & & & \\ S1 \\ G1 \\ S2 \\ G2 \\ & & & \\ G2 \\ & & & \\ \end{array}$

SOP-8



N-Channel MOSFET

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	ID	10	A
Drain Current-Continuous(Tc=100℃)	I₀ (100 °C)	6.4	A
Pulsed Drain Current	Іл	40	A
Maximum Power Dissipation	PD	2	w
Operating Junction and Storage Temperature Range	Тյ,Тѕтс	-55 To 150	°C
Thermal Resistance, Junction-to-Ambient (Note 2)	Reja	62.5	°C/W

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N-CH Electrical Characteristics (T_A=25 $^\circ\!\mathrm{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	40	-	-	V
Zero Gate Voltage Drain Current	Idss	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	lgss	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	V _{DS} =V _{GS} ,I _D =250µA	1	1.5	2.0	V
		V_{GS} =10V, I _D =8A	-	15	20	mΩ
Drain-Source On-State Resistance	Rds(on)	V_{GS} =4.5V, I _D =4A	-	20	30	mΩ
Forward Transconductance	gfs	V _{DS} =5V,I _D =8A	33	-	-	S
Input Capacitance	Clss		-	964	-	PF
Output Capacitance	Coss	V _{DS} =20V,V _{GS} =0V,	-	109	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	96	-	PF
Turn-on Delay Time	td(on)		-	5.5	-	nS
Turn-on Rise Time	tr	V _{DD} =20V, RL=2.5Ω	-	14	-	nS
Turn-Off Delay Time	td(off)	V_{GS} =10V, R_{GEN} =3 Ω	-	24	-	nS
Turn-Off Fall Time	tr		-	12	-	nS
Total Gate Charge	Qg		-	22.9	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =20V,I _D =8A,	-	3.5	-	nC
Gate-Drain Charge	Qgd	V _{GS} =10V	-	5.3	-	nC
Diode Forward Voltage (Note 3)	Vsd	V _{GS} =0V,I _S =9A	-	0.8	1.2	V



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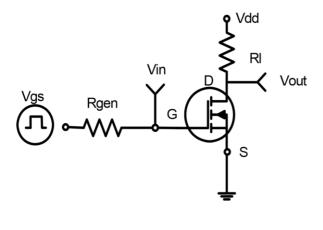


Figure 1:Switching Test Circuit

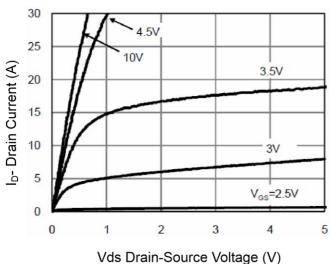
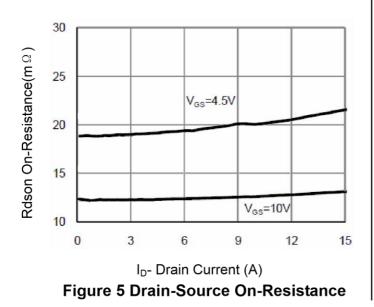


Figure 3 Output Characteristics



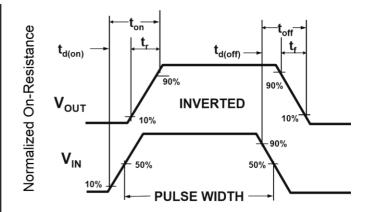
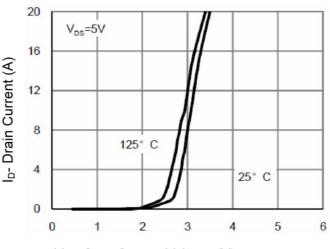
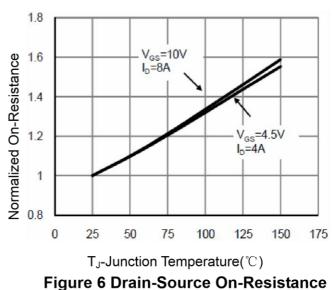


Figure 2:Switching Waveforms



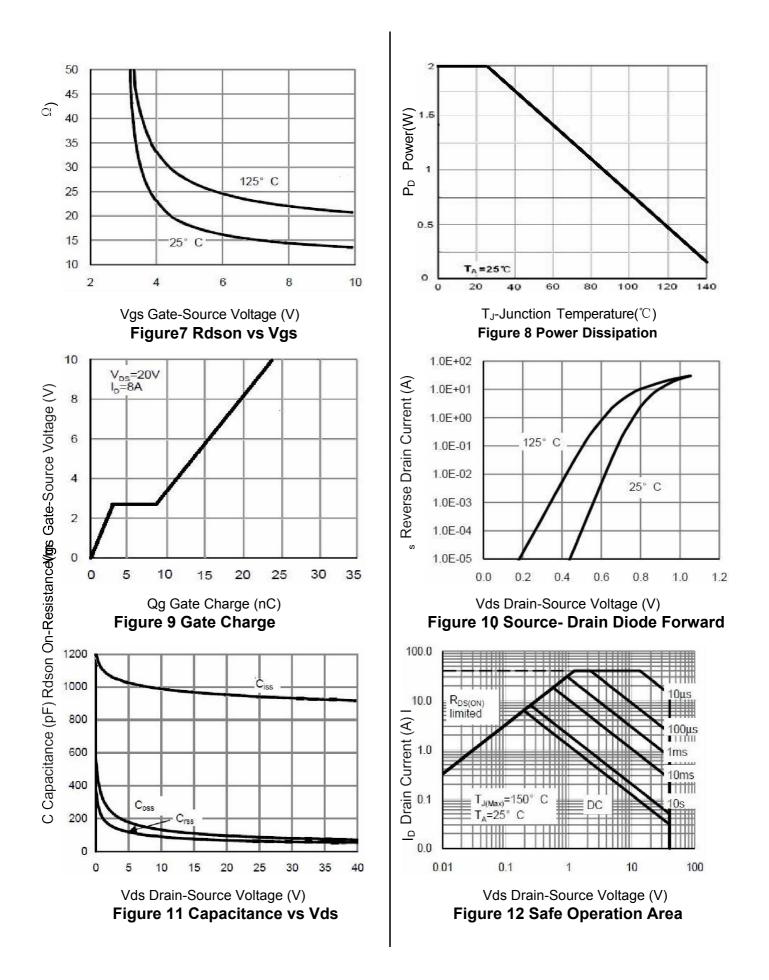
Vgs Gate-Source Voltage (V) Figure 4 Transfer Characteristics





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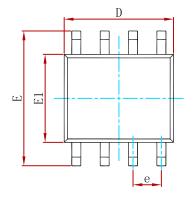
HF

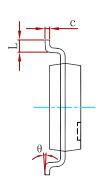


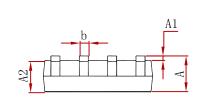


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PACKAGE MECHANICAL DATA

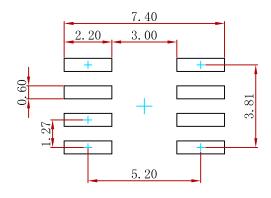






Symbol	Dimensions In	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max		
А	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
b	0.330	0.510	0.013	0.020		
с	0.170	0.250	0.007	0.010		
D	4.800	5.000	0.189	0.197		
e	1.270 ((BSC)	0.050	(BSC)		
E	5.800	6.200	0.228	0.244		
E1	3.800	4.000	0.150	0.157		
L	0.400	1.270	0.016	0.050		
θ	0 °	8°	0 °	8°		

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
AO4884-MS	SOP-8	4000





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